

ADL 奥德利® AUDLEY FP5N65	TO-220 <p>1. Gate (G) 2. Drain (D) 3. Source (S)</p>
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Absolute Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{DSS}	Drain-Source Voltage	650	V
I_D	Drain Current	$T_j=25^\circ\text{C}$	5
		$T_j=100^\circ\text{C}$	2.8
$V_{GS(TH)}$	Gate Threshold Voltage	± 30	V
E_{AS}	Single Pulse Avalanche Energy (note1)	260	mJ
I_{AR}	Avalanche Current (note2)	5	A
P_D	Power Dissipation ($T_j=25^\circ\text{C}$)	120	W
T_j	Junction Temperature(Max)	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^\circ\text{C}$
T_L	Maximum lead temperature for soldering purpose, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}$	Thermal Resistance,Junction to Case	-	1.18	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance,Junction to Ambient	-	62.5	$^\circ\text{C}/\text{W}$

Electrical Characteristics (Ta=25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
Off Characteristics						
BVDSS	Drain-Source Breakdown Voltage	Id=250µA, VGS=0	650	-	-	V
ΔBVDSS/ΔTJ	Breakdown Voltage Temperature Coefficient	Id=250µA ,Reference to 25°C	-	0.6	-	V/°C
IDSS	Zero Gate Voltage Drain Current	VDS=650V, VGS=0V	-	-	10	µA
		VDS=480V, TJ=125°C			100	
IGSSF	Gate-body leakage Current, Forward	VGS=+30V, VDS=0V	-	-	100	nA
IGSSR	Gate-body leakage Current, Reverse	VGS=-30V, VDS=0V	-	-	-100	
On Characteristics						
VGS(TH)	Date Threshold Voltage	Id=250µA, VDS=VGS	2	-	4	V
RDS(ON)	Static Drain-Source On-Resistance	Id=2.5A, VGS=10V	-	-	2.3	Ω
Dynamic Characteristics						
Ciss	Input Capacitance	VDS=25V, VGS=0, f=1.0MHz	-	520	670	pF
Coss	Output Capacitance		-	70	90	
Crss	Reverse Transfer Capacitance		-	8	11	
Switching Characteristics						
Td(on)	Turn-On Delay Time	VDD=300V, ID=5A RG=25Ω (Note 3,4)	-	13	35	ns
Tr	Turn-On Rise Time		-	45	100	
Td(off)	Turn-Off Delay Time		-	25	60	
Tf	Turn-Off Rise Time		-	35	80	
Qg	Total Gate Charge	VDS=480V, VGS=10V, ID=5A (Note 3,4)	-	15	20	nC
Qgs	Gate-Source Charge		-	3.4	-	
Qgd	Gate-Drain Charge		-	7.1	-	
Drain-Source Diode Characteristics and Maximum Ratings						
Is	Max. Diode Forward Current	-	-	-	5	A
ISM	Max. Pulsed Forward Current	-	-	-	16	
VSD	Diode Forward Voltage	ID=5A	-	-	1.35	V
Trr	Reverse Recovery Time	Is=5A, VGS =0V diF/dt=100A/µs (Note3)	-	250	-	nS
Qrr	Reverse Recovery Charge		-	1.5	-	µC

Notes : 1, L=32.5mH, IAS=5A, VDD=50V, RG=25Ω, Starting TJ =25°C

2, Repetitive Rating : Pulse width limited by maximum junction temperature

3, Pulse Test : Pulse Width ≤ 300µs, Duty Cycle ≤ 2%

4, Essentially Independent of Operating Temperature

Typical Characteristics

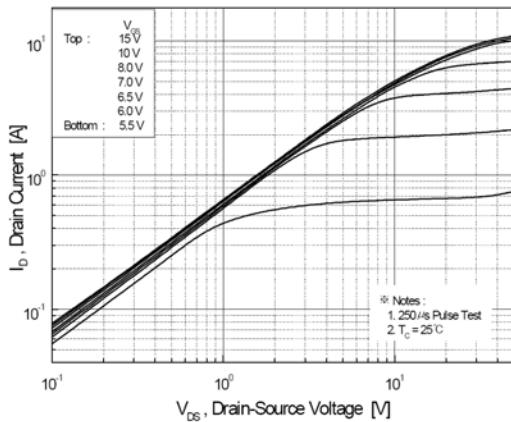


Figure 1. On-Region Characteristics

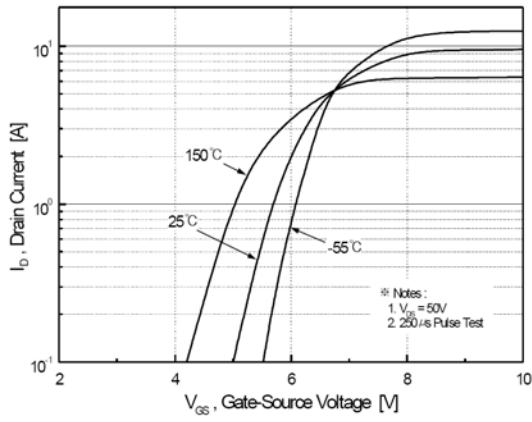


Figure 2. Transfer Characteristics

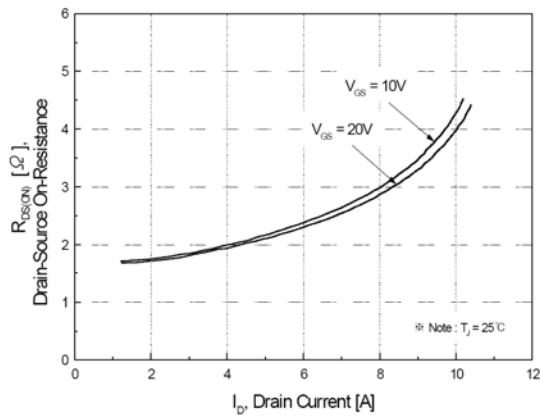


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

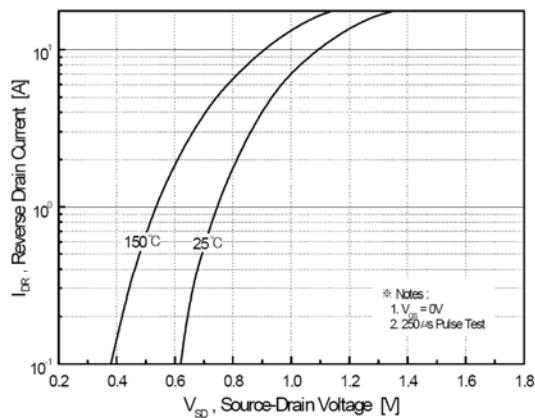


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

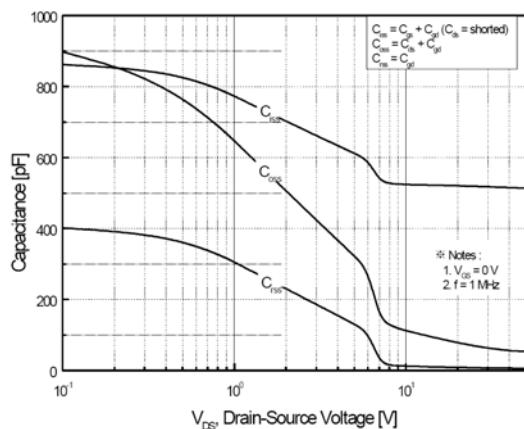


Figure 5. Capacitance Characteristics

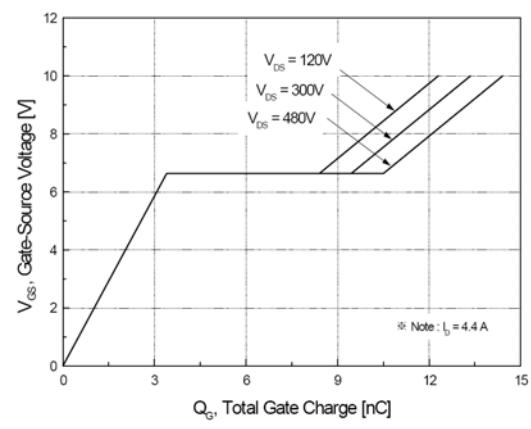


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

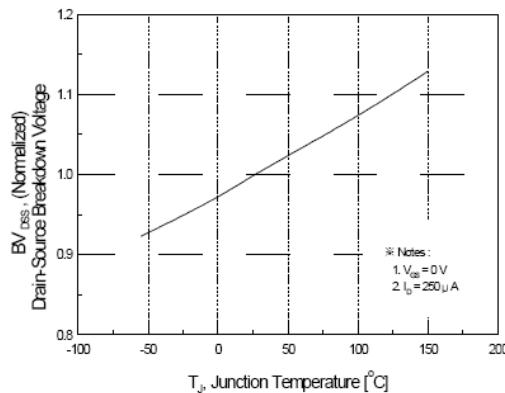


Figure 7. Breakdown Voltage Variation vs Temperature

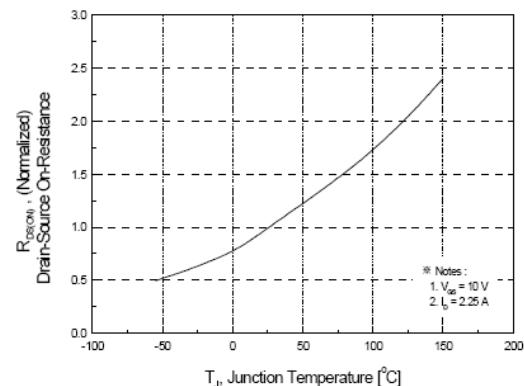


Figure 8. On-Resistance Variation vs Temperature

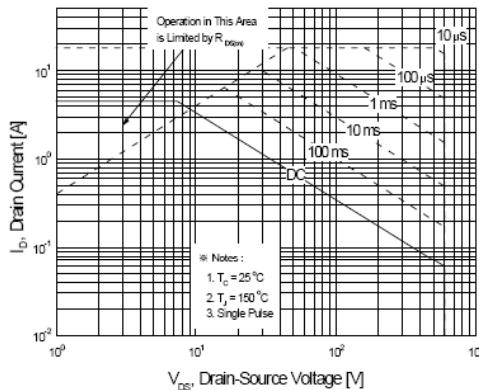


Figure 9. Maximum Safe Operating Area

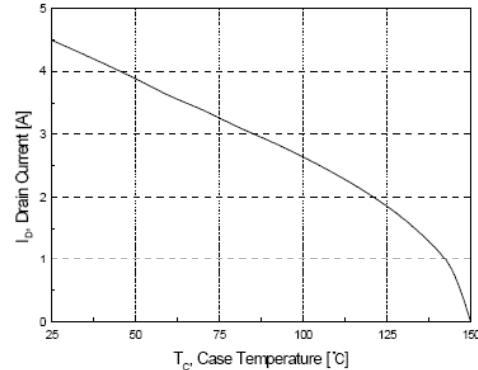


Figure 10. Maximum Drain Current vs Case Temperature

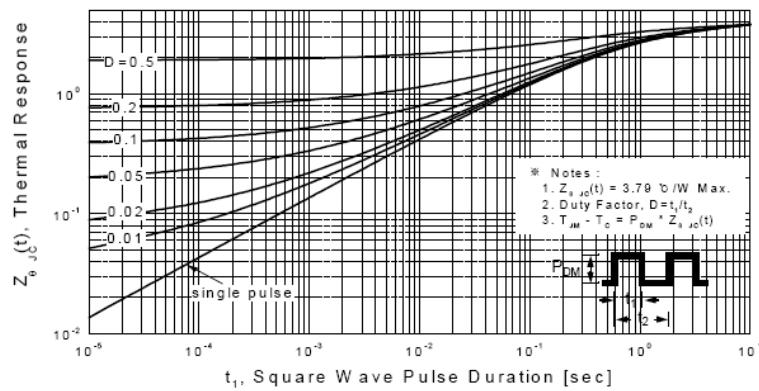
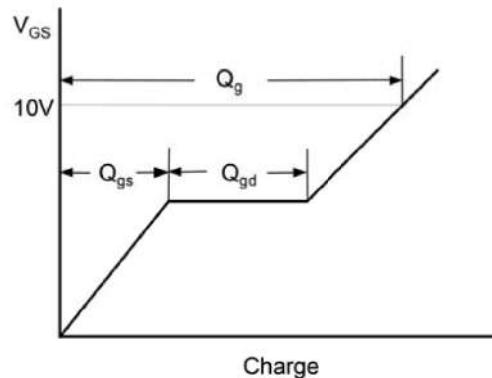
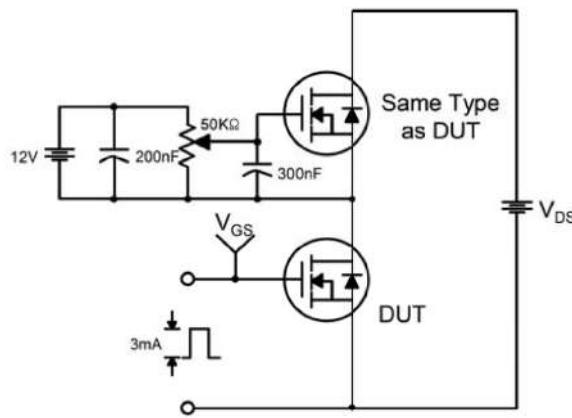
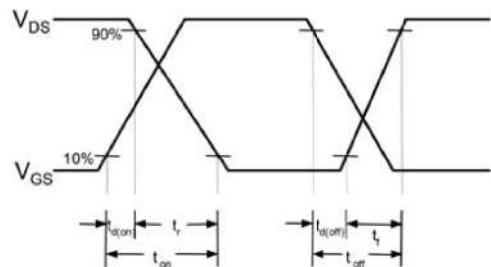
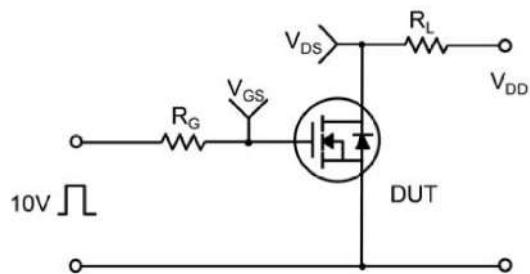


Figure 11. Transient Thermal Response Curve

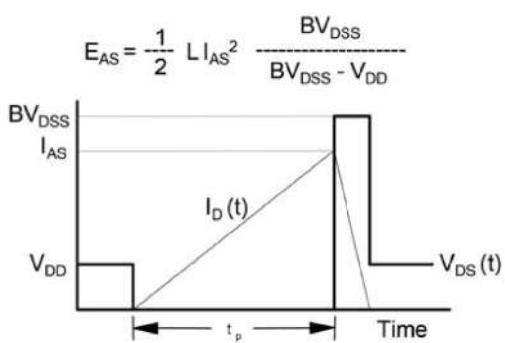
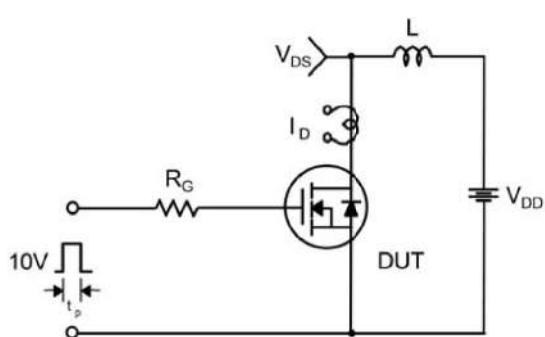
Gate Charge Test Circuit & Waveform



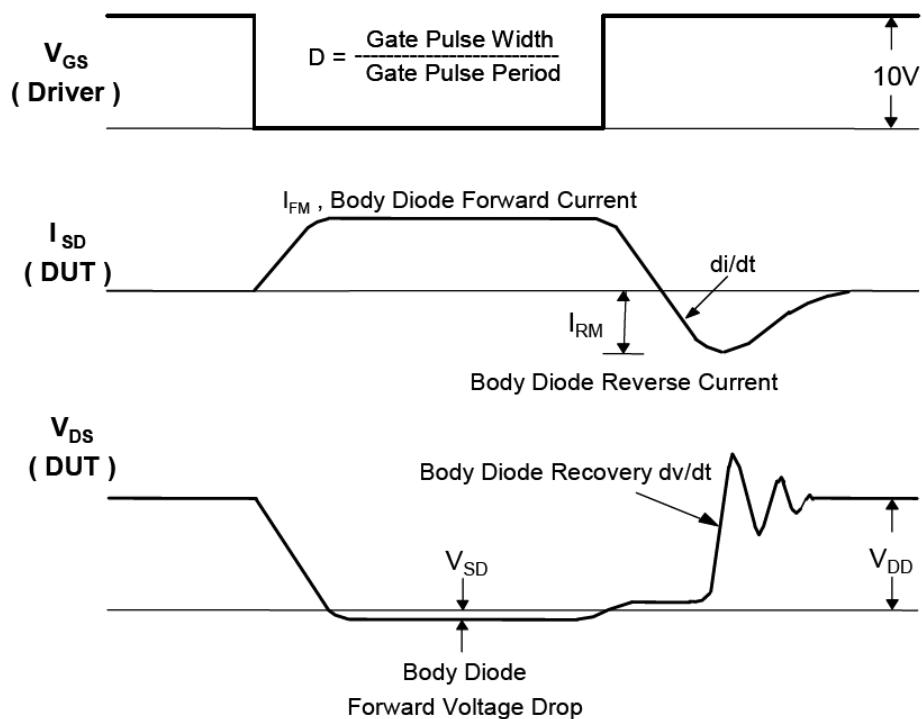
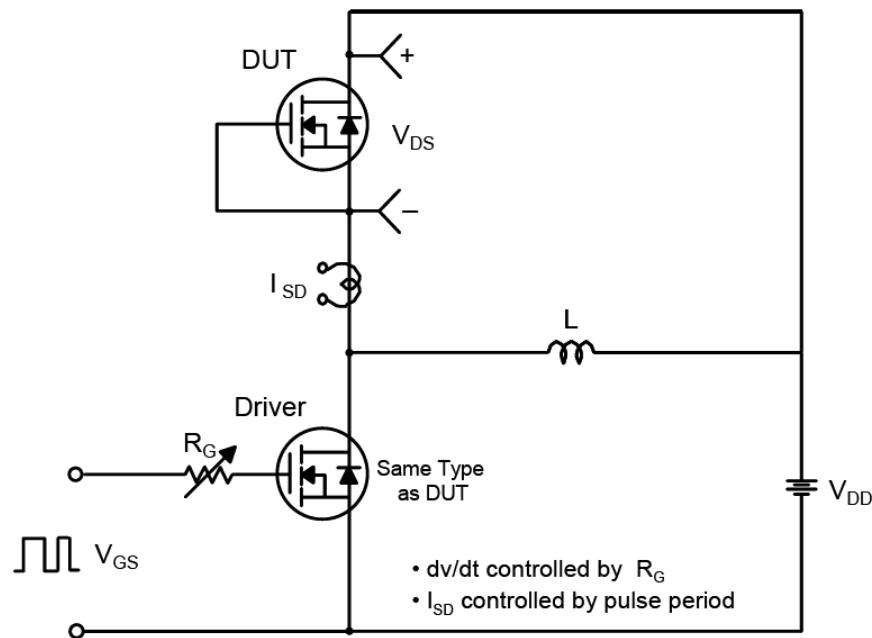
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching Test Circuit & Waveforms



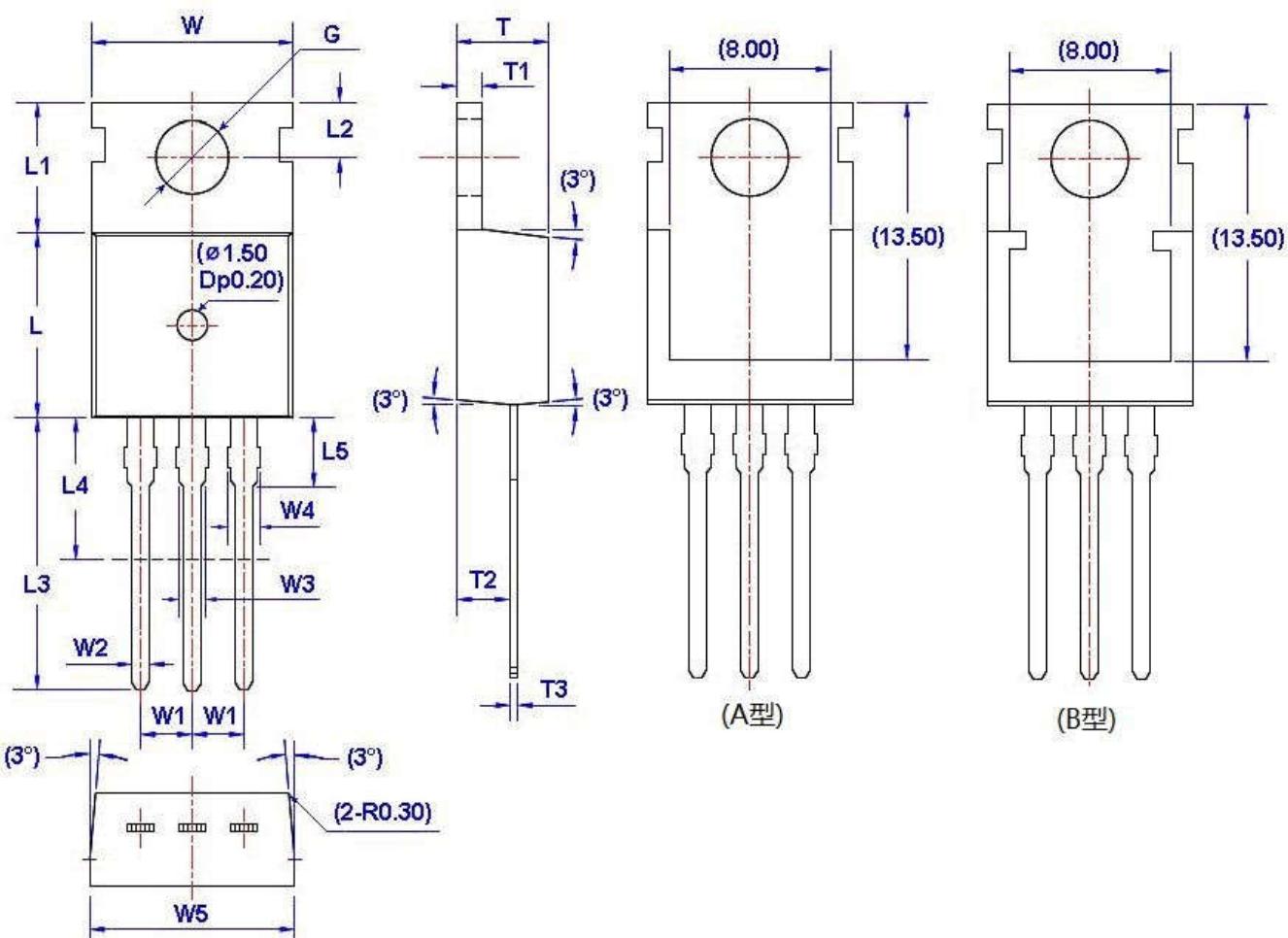
Peak Diode Recovery dv/dt Test Circuit & Waveform



Package Dimension

TO-220

Unit: mm



Symbol	Size		Symbol	Size		Symbol	Size		Symbol	Size	
	Min	Max		Min	Max		Min	Max		Min	Max
W	9.66	10.28	W5	9.80	10.20	L4**	6.20	6.60	T3	0.45	0.60
W1	2.54 (TYP)		L	9.00	9.40	L5	2.79	3.30	G(Φ)	3.50	3.70
W2	0.70	0.95	L1	6.40	6.80	T	4.30	4.70			
W3	1.17	1.37	L2	2.70	2.90	T1	1.15	1.40			
W4*	1.32	1.72	L3	12.70	14.27	T2	2.20	2.60			